80dB(typ)



# LM4894 Boomer® Audio Power Amplifier Series

# 1 Watt Fully Differential Audio Power Amplifier With Shutdown Select

## **General Description**

The LM4894 is a fully differential audio power amplifier primarily designed for demanding applications in mobile phones and other portable communication device applications. It is capable of delivering 1 watt of continuous average power to an  $8\Omega$  BTL load with less than 1% distortion (THD+N) from a  $5V_{DC}$  power supply.

Boomer audio power amplifiers were designed specifically to provide high quality output power with a minimal amount of external components. The LM4894 does not require output coupling capacitors or bootstrap capacitors, and therefore is ideally suited for mobile phone and other low voltage applications where minimal power consumption is a primary requirement.

The LM4894 features a low-power consumption shutdown mode. To facilitate this, Shutdown may be enabled by either logic high or low depending on mode selection. Driving the shutdown mode pin either high or low enables the shutdown select pin to be driven in a likewise manner to enable Shutdown. Additionally, the LM4894 features an internal thermal shutdown protection mechanism.

The LM4894 contains advanced pop & click circuitry which eliminates noises which would otherwise occur during turn-on and turn-off transitions.

The LM4894 is unity-gain stable and can be configured by external gain-setting resistors.

# Key Specifications Improved PSRR at 217Hz

•	( ) ( )
■ Power Output at 5.0V & 1% THD	1.0W(typ)
■ Power Output at 3.3V & 1% THD	400mW(typ)
■ Shutdown Current	0.1µA(typ)

#### **Features**

- Fully differential amplification
- Available in space-saving packages micro SMD, MSOP, and LLP
- Ultra low current shutdown mode
- Can drive capacitive loads up to 500 pF
- Improved pop & click circuitry eliminates noises during turn-on and turn-off transitions
- 2.2 5.5V operation
- No output coupling capacitors, snubber networks or bootstrap capacitors required
- Unity-gain stable
- External gain configuration capability
- Shutdown high or low selectivity
- High CMRR

# **Applications**

- Mobile phones
- PDAs
- Portable electronic devices

# **Typical Application**

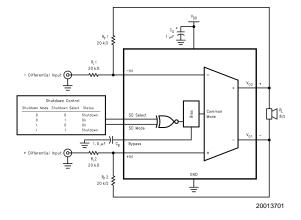
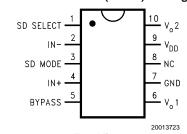


FIGURE 1. Typical Audio Amplifier Application Circuit

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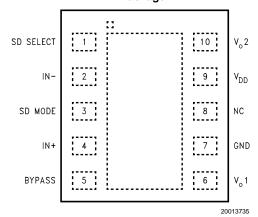
# **Connection Diagrams**

### Mini Small Outline (MSOP) Package



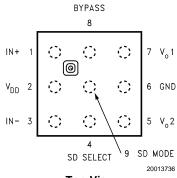
Top View Order Number LM4894MM See NS Package Number MUB10A

### LLP Package



Top View Order Number LM4894LD See NS Package Number LDA10B

### 9 Bump micro SMD Package



Top View Order Number LM4894IBP See NS Package Number BPA09CDB

# **Absolute Maximum Ratings** (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage 6.0V Storage Temperature -65°C to +150°C Input Voltage -0.3V to  $V_{DD}$  +0.3V Power Dissipation (Note 3) Internally Limited ESD Susceptibility (Note 4) 2000V ESD Susceptibility (Note 5) 200V

Junction Temperature Thermal Resistance

 $\theta_{JC}$  (LLP) 12°C/W  $\theta_{JA}$  (LLP) 63°C/W

$\theta_{JA}$ (micro SMD)	220°C/W
$\theta_{JC}$ (MSOP)	56°C/W
θ <sub>IA</sub> (MSOP)	190°C/W

Soldering Information

See AN-1112 'microSMD Wafers Level Chip Scale

Package.'

See AN-1187 'Leadless Leadframe Package (LLP).'

# Operating Ratings

Temperature Range

 $-40^{\circ}C \leq T_A \leq 85^{\circ}C$  $T_{MIN} \leq T_A \leq T_{MAX}$ Supply Voltage  $2.2V \le V_{DD} \le 5.5V$ 

# Electrical Characteristics $V_{DD} = 5V$

The following specifications apply for  $V_{DD} = 5V$ ,  $A_{V} = 1$ , and  $8\Omega$  load unless otherwise specified. Limits apply for T<sub>A</sub> = 25°C.

Symbol	Parameter	Conditions	LM4894		
			Typical	Limit	Units (Limits)
			(Note 6)	(Note 7)	(Lillins)
I <sub>DD</sub>	Quiescent Power Supply Current	$V_{IN} = 0V$ , $I_o = 0A$	4	8	mA (max)
I <sub>SD</sub>	Shutdown Current	V <sub>shutdown</sub> = GND	0.1	1	μA (max)
Po	Output Power	THD = 1% (max); f = 1 kHz			
		LM4894LD, $R_L$ = $4\Omega$ (Note 11)	1.4		W (min)
		LM4894, $R_L = 8\Omega$	1	0.850	
THD+N	Total Harmonic Distortion+Noise	$P_o = 0.4 \text{ Wrms}; f = 1 \text{kHz}$	0.1		%
PSRR	Power Supply Rejection Ratio	V <sub>ripple</sub> = 200mV sine p-p			
		f = 217Hz (Note 9)	87		dB
		f = 1kHz (Note 9)	83		]
		f = 217Hz (Note 10)	83		]
		f = 1kHz (Note 10)	80		]
CMRR	Common_Mode Rejection Ratio	f = 217Hz	50		dB

150°C

Electrical Characteristics  $V_{DD} = 3V$  (Notes 1, 2, 8) The following specifications apply for  $V_{DD} = 3V$ ,  $A_V = 1$ , and  $8\Omega$  load unless otherwise specified. Limits apply for  $T_A = 25^{\circ}C$ .

			LM4894		11.24
Symbol	Parameter	Conditions	Typical	Limit	Units (Limits)
			(Note 6)	(Note 7)	(Lillins)
I <sub>DD</sub>	Quiescent Power Supply Current	$V_{IN} = 0V$ , $I_o = 0A$	3.5	6	mA (max)
I <sub>SD</sub>	Shutdown Current	$V_{\overline{\text{shutdown}}} = GND$	0.1	1	μA (max)
Po	Output Power	THD = 1% (max); f = 1kHz	0.35		W
THD+N	Total Harmonic Distortion+Noise	$P_o = 0.25$ Wrms; $f = 1$ kHz	0.325		%
PSRR	Power Supply Rejection Ratio	V <sub>ripple</sub> = 200mV sine p-p			
		f = 217Hz (Note 9)	87		dB
		f = 1kHz (Note 9)	83		
		f = 217Hz (Note 10)	80		
		f = 1kHz (Note 10)	78		
CMRR	Common-Mode Rejection Ratio	f = 217Hz	49		dB
	*				

Electrical Characteristics  $V_{DD} = 3V$  (Notes 1, 2, 8) The following specifications apply for  $V_{DD} = 3V$ ,  $A_V = 1$ , and  $8\Omega$  load unless otherwise specified. Limits apply for  $T_A = 1$ 25°C. (Continued)

Note 1: All voltages are measured with respect to the ground pin, unless otherwise specified.

Note 2: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

Note 3: The maximum power dissipation must be derated at elevated temperatures and is dictated by T<sub>JMAX</sub>,  $\theta_{JA}$ , and the ambient temperature T<sub>A</sub>. The maximum allowable power dissipation is  $P_{DMAX} = (T_{JMAX} - T_A)/\theta_{JA}$  or the number given in Absolute Maximum Ratings, whichever is lower. For the LM4894, see power derating currents for additional information.

**Note 4:** Human body model, 100 pF discharged through a 1.5 k $\Omega$  resistor.

Note 5: Machine Model, 220 pF-240 pF discharged through all pins.

Note 6: Typicals are measured at 25°C and represent the parametric norm.

Note 7: Datasheet min/max specification limits are guaranteed by design, test, or statistical analysis.

Note 8: For micro SMD only, shutdown current is measured in a Normal Room Environment. Exposure to direct sunlight will increase ISD by a maximum of 2µA.

Note 9: Unterminated input.

Note 10:  $10\Omega$  terminated input.

Note 11: When driving  $4\Omega$  loads from a 5V supply, the LM4894LD must be mounted to a circuit board.

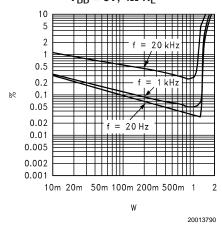
## **External Components Description**

(Figure 1)

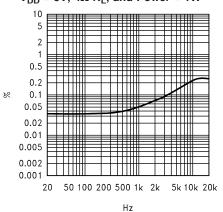
Comp	onents	Functional Description
1.	R <sub>i</sub>	Inverting input resistance which sets the closed-loop gain in conjunction with R <sub>f</sub> .
2.	R <sub>f</sub>	Feedback resistance which sets the closed-loop gain in conjunction with R <sub>i</sub> .
3.	Cs	Supply bypass capacitor which provides power supply filtering. Refer to the <b>Power Supply Bypassing</b> section for information concerning proper placement and selection of the supply bypass capacitor.
4.	СВ	Bypass pin capacitor which provides half-supply filtering. Refer to the section, <b>Proper Selection of External Components</b> , for information concerning proper placement and selection of C <sub>B</sub> .

# **Typical Performance Characteristics LD Specific Characteristics**

LM4894LD THD+N vs Output Power  $V_{DD} = 5V, 4\Omega R_{I}$ 



LM4894LD THD+N vs Frequency  $V_{DD}$  = 5V,  $4\Omega$  R<sub>L</sub>, and Power = 1W



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# Application Information (Continued)

duce peaks in excess of 1W without producing audible distortion. At this time, the designer must make sure that the power supply choice along with the output impedance does not violate the conditions explained in the **Power Dissipation** section. Once the power dissipation equations have been addressed, the required differential gain can be determined from Equation 7.

$$A_{VD} \ge \sqrt{(P_0 R_L)}/(V_{IN}) = V_{orms}/V_{inrms}$$
(8)

$$R_f / R_i = A_{VD}$$

From Equation 7, the minimum  $A_{VD}$  is 2.83. Since the desired input impedance was  $20k\Omega$ , a ratio of 2.83:1 of  $R_f$  to  $R_i$ 

results in an allocation of  $R_i=20 k\Omega$  for both input resistors and  $R_f\!\!=60 k\Omega$  for both feedback resistors. The final design step is to address the bandwidth requirement which must be stated as a single -3dB frequency point. Five times away from a -3dB point is 0.17dB down from passband response which is better than the required  $\pm 0.25 dB$  specified.

$$f_H = 20kHz * 5 = 100kHz$$

The high frequency pole is determined by the product of the desired frequency pole,  $f_{\rm H}$ , and the differential gain,  $A_{\rm VD}$ . With a  $A_{\rm VD}=2.83$  and  $f_{\rm H}=100 {\rm kHz}$ , the resulting GBWP = 150 kHz which is much smaller than the LM4894 GBWP of 10 MHz. This figure displays that if a designer has a need to design an amplifier with a higher differential gain, the LM4894 can still be used without running into bandwidth limitations.

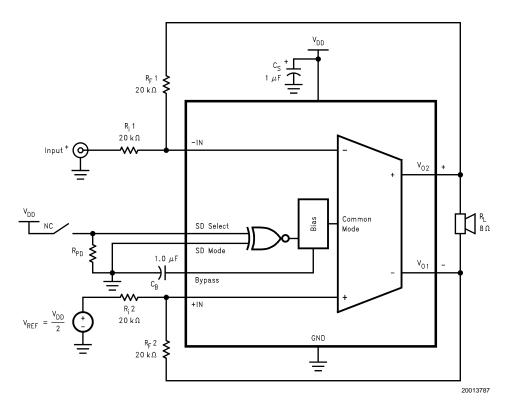


FIGURE 2. Single-Ended Input, 'Shutdown-Low' Configuration

# Application Information (Continued)

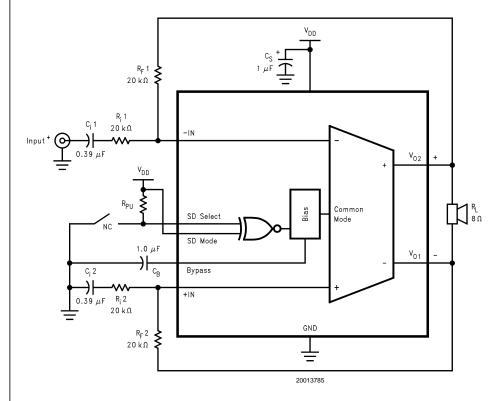


FIGURE 3. Single-Ended Input, 'Shutdown-High' Configuration

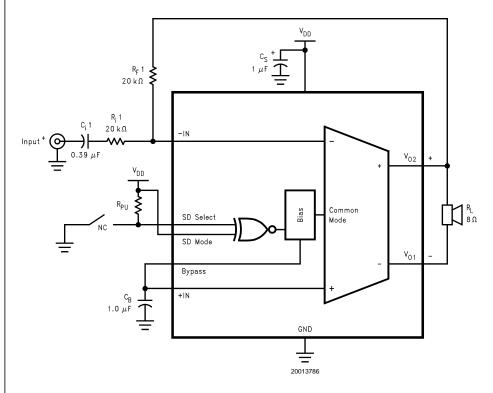


FIGURE 4. Single-Ended Input, 'Shutdown-High' Configuration